

# AMP2065B SOLID STATE HIGH POWER AMPLIFIER

## FEATURES

- Class AB linear GaN hybrid design
- Instantaneous ultra-wide bandwidth
- Solid-state TWT replacement
- Small form factor, light weight rack mounted system
- Designed for broadband EMI/RFI, Lab, Communication applications
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



## ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	6.0 - 18.0 GHz	
Power Output @ Psat	300 Watt Min	CW
Power Gain	55 dB Min	Nominal Pin = 0dBm
Power Gain Flatness	5 dB p-p Max	Constant input power
Input / Output Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	44dBm/Tone, Δ = 1MHz
Harmonics	<-20 dBc Typ	At rated output
Spurious	-60 dBc Max	Non-harmonic
AC Power	180 - 260 VAC, 3-Phase, 47 - 63 Hz	
Power Consumption	<5000 Watt Typ	At rated output
Input Power Protection	+3 dBm Max	<10 Sec without damage
Load VSWR Protection	5 : 1 Max	<1 minute at rated min Pout

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	482 x 311 x 600 mm	R7U rack mount chassis
Weight	50 Kg.	Typical
RF Connectors In/Out	Precision N Female / WRD650	Front Panel Standard
AC Connector	IEC 60320-C14	Or equivalent
Cooling	Built in Fan Cooling	Variable speed
<b>EMI-SERIES:</b> Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, USB Optional GPIB Interface	

## OUTLINE DRAWING

